

# Methoden moderner Röntgenphysik I: Struktur und Dynamik kondensierter Materie

Vorlesung zum Haupt/Masterstudiengang Physik

WS 2009/10

G. Grübel, M. Martins, E. Weckert et al.

Location: SemRm 4, Physik, Jungiusstrasse

Thursdays 10.15 – 11.45

G.Grübel (GG), A.Meents (AM), C. Gutt (CG)

# Methoden moderner Röntgenphysik I: Struktur und Dynamik kondensierter Materie

## Hard X-Rays - Introduction into X-ray physics - Lecture 3

22.10.	Introduction	(GG)
29.10.	X-ray Scattering Primer, Sources of X-rays	(GG)
5.11.	Refraction and Reflexion, Kinematical Scattering (I)	(GG)
12.11.	Kinematical Scattering Theory (II)	(GG)
19.11.	Applications of KST and “perfect” crystals	(GG)
26.11.	Small Angle and Anomalous Scattering	(GG)
3.12. - 7. 1.	Modern Crystallography	(AM)
14. 1. - 4. 2.	Coherence base techniques	(CG)

# Coherence of light and matter I: from basic concepts to modern applications

Introduction into X-ray physics: 22.10.-26.11.

## Introduction

Overview, Introduction to X-ray scattering

## X-ray Scattering Primer and Sources of X-rays

Elements of X-ray scattering, sources of X-rays

## Reflection and Refraction, Kinematical Diffraction (I)

Snell's law, Fresnel equations, diffraction from an atom, molecule, crystal,...

## Kinematical Diffraction (II)

Reciprocal lattice, structure factor,...

## Applications of Kinematical Diffraction and “perfect” crystals

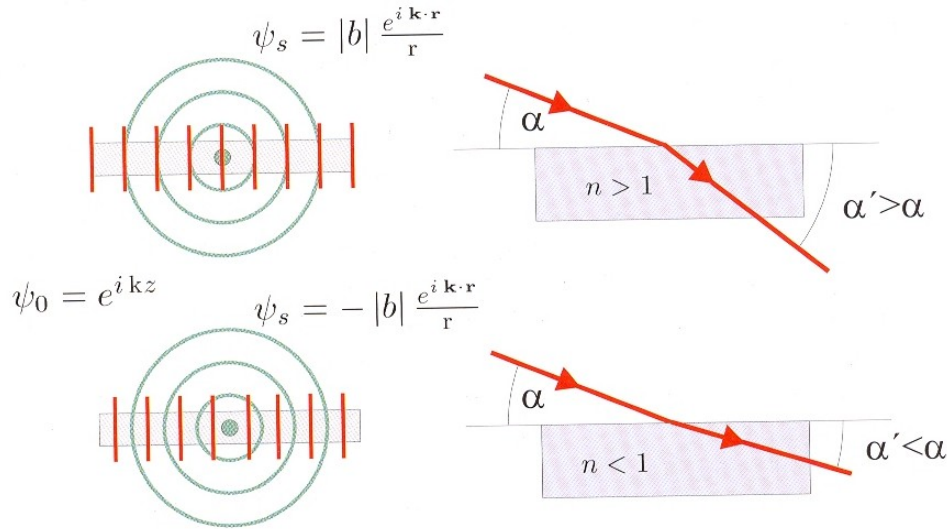
Quasiperiodic lattices, crystal truncation rods, lattice vibrations, Debye-Waller factor, “perfect” crystal theory

## SAXS, Anomalous Diffraction

Introduction into small angle scattering and anomalous scattering

# Refraction and Reflexion from Interfaces

# Refraction and Reflexion from Interfaces



Rays of light propagating in air change direction when entering glass, water or another transparent material.

Governed by Snell's law:

$$\cos \alpha / \cos \alpha' = n \text{ (refractive index)}$$

$$n = n(\omega) \quad 1.2 < n < 2 \text{ visible light}$$

$$n < 1 \text{ X-rays } (\alpha' < \alpha)$$

$$n = 1 - \delta \quad \delta \approx 10^{-5}$$

Note: spherical wave  $\exp(i\mathbf{k}'\cdot\mathbf{r})$

$$k' = nk = (n/c)\omega = \omega/v$$

with  $v=c/n$  phase velocity

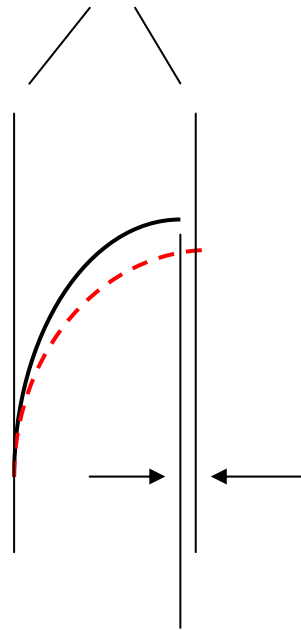
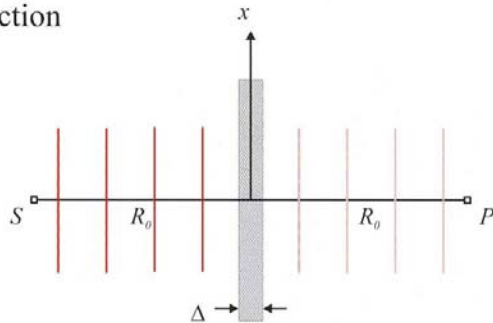
( $v > c$  for  $n < 1$ ; but group velocity  $d\omega/dk \leq c$ )

total external reflexion:

for  $\alpha < \alpha_c$  (critical angle)

# Refractive Index

Refraction



Phase difference

## Refractive picture:

Consider plane wave impinging on a slab with thickness  $\Delta$  and refractive index  $n$ . Evaluate amplitude at observation point  $P$  (compared to the situation without slab).

$$\left. \begin{array}{l} \text{no slab: } \exp(ik\Delta) \\ \text{slab: } \exp(ink\Delta) \end{array} \right\} \begin{array}{l} \text{phase difference:} \\ \exp(i(nk-k)\Delta) \end{array}$$

amplitude:

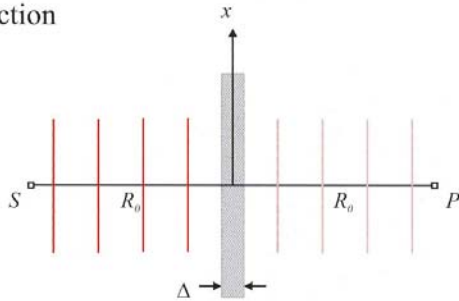
$$\begin{aligned} \Psi_{\text{tot}}^P / \Psi_0^P &= \exp(ink\Delta) / \exp(ik\Delta) \\ &= \exp(i(nk-k)\Delta) \end{aligned}$$

$$\exp(i\alpha) = \cos\alpha + i\sin\alpha \xrightarrow{\alpha \text{ small}} 1+i\alpha$$

$$\Psi_{\text{tot}}^P \approx \Psi_0^P [1 + i(n-1)k\Delta] \quad (\$)$$

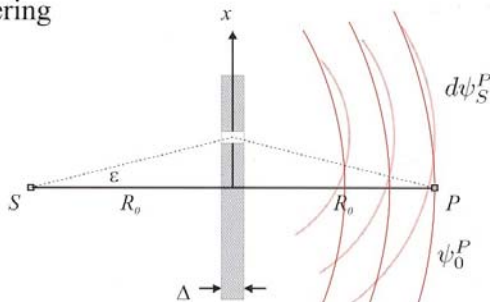
# Refractive Index

Refraction



$$\psi_{tot}^P = \psi_0^P e^{i(nk-k)\Delta} \approx \psi_0^P [1 + i(n-1)k\Delta]$$

Scattering



$$\phi(x, y) = k(2R - 2R_0) \approx k(x^2 + y^2)/R_0$$

$$d\psi_S^P = \left(\frac{e^{ikR_0}}{R_0}\right) \text{ incident wave}$$

$$(\rho \Delta dx dy) \text{ number of scatterers}$$

$$\left(-b \frac{e^{ikR_0}}{R_0}\right) \text{ spherical wave from one scatterer}$$

$$e^{i\phi(x,y)} \text{ apart from this phase factor}$$

$$\psi_{tot}^P = \psi_0^P + \int d\psi_s^P = \psi_0^P \left[1 - i \frac{2\pi \rho b \Delta}{k}\right]$$

Scattering picture:

$$R = \sqrt{R_0^2 + x^2} = \sqrt{R_0^2(1 + x^2/R_0^2)}$$

$$\approx R_0 \sqrt{1 + x^2/R_0^2} \approx R_0 \left[1 + \frac{x^2}{2R_0^2}\right]$$

$$= R_0 \sqrt{[1 + x^2/2R_0^2]^2} = R_0 [1 + x^2/2R_0^2]$$

phase difference ( $2kR$ ) btw. direct rays and rays following path  $R$ ;

$$2kx^2/2R_0 = kx^2/R_0$$

include y direction:

$$\exp(i\Phi(x,y)) = \exp(i(x^2+y^2)k/R_0)$$

amplitude at P:

$$d\psi_S^P \approx$$

$$\exp(ikR_0)/R_0 \quad (\rho \Delta dx dy) \quad (b \exp(ikR_0)/R_0) \quad \exp(i\Phi(x,y))$$

incident wave

number of scatters  
in volume element  
 $\rho dx dy$

scattered wave  
from 1 scatterer

phase factor

# Refractive Index

$$\Psi_S^P = \int d\Psi_S^P = -\rho b \Delta \{ \exp(i2kR_0) \} / R_0^2 \cdot \frac{\int \exp(i\Phi(x,y)) dx dy}{i\pi R_0 / k} \quad [\text{Ref. 1}]$$

Amplitude at P without slab:

$$\Psi_0^P = \{ \exp(ik2R_0) \} / 2R_0$$

$$\Psi_{\text{tot}}^P = \Psi_0^P [1 - i2\pi\rho b \Delta / k] \equiv (\$) \equiv \Psi_0^P [1 + i(n-1)k\Delta]$$

$$\rightarrow n = 1 - 2\pi\rho b / k^2 = 1 - \delta$$

If a homogeneous electron density  $\rho$  is replaced by a plate composed of atoms:

$$\rho = \rho_a f^0(0)$$

Number density x atomic scattering factor

$$\delta = 2\pi\rho_a f^0(0) r_0 / k^2$$

Total external reflexion ( $\alpha'=0$ ) for  $\alpha = \alpha_c$ :

$$\cos\alpha = n \cos\alpha'$$

$$\cos\alpha_c = 1 - \delta = 1 - \alpha_c^2 / 2$$

$$\alpha_c = \text{sqrt}(2\delta) = \text{sqrt}(4\pi\rho r_0 / k^2)$$

$$k=2\pi/\lambda=4\text{\AA}^{-1}, b=r_0=2.82 \times 10^{-5}\text{\AA}, \rho=1e^{-}/\text{\AA}^3: \delta \approx 10^{-5}$$

[Ref. 1: Als-Nielsen & McMorrow p.66]



# critical angle for Si

$$\alpha_c = \sqrt{2\delta} = \sqrt{4\pi\rho r_0/k^2}$$

Silicon:  $\rho = 0.699 \text{ e-}/\text{\AA}^3$ ,  $\lambda = 1\text{\AA}$

$$\alpha_c = \sqrt{4\pi \times 0.699 \times 2.82\text{e-}5 \times 1/(2\pi)^2}$$

$$= 0.0025 \text{ rad}$$

$$Q_c = (4\pi/\lambda) \sin\alpha_c = 0.032 \text{ \AA}^{-1}$$

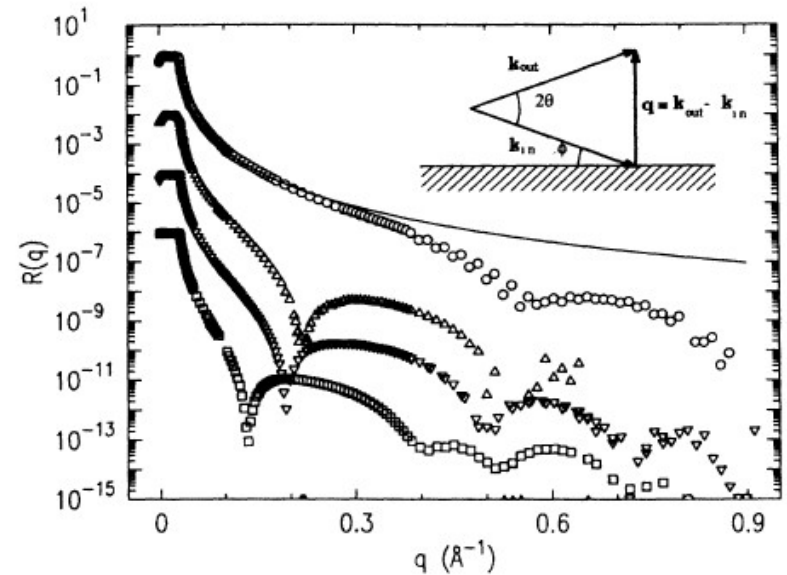
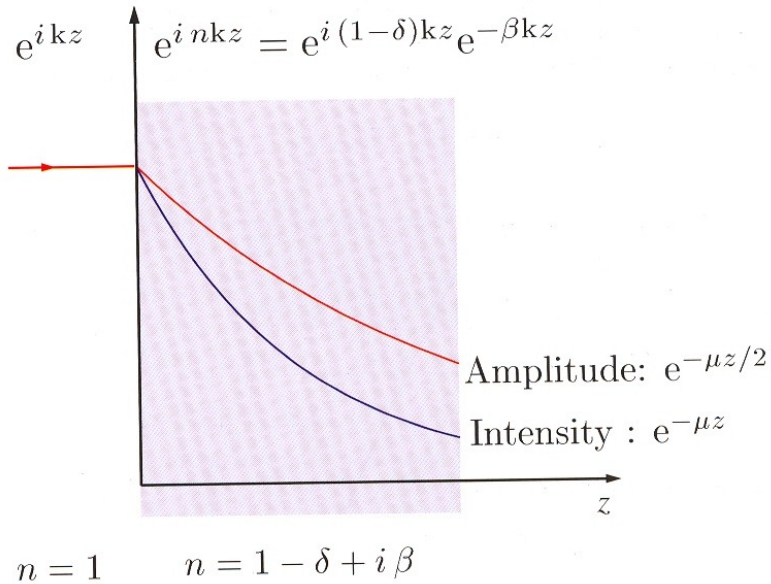


FIG. 1. Normalized reflectivity data from several samples. Successive data sets are displaced by 100 times and error bars omitted for clarity. (—) Theoretical reflectivity from an ideal step interface with bulk silicon density. (○) Uncoated silicon sample in helium; the “pairing” of points occurs for two scans taken 60 min apart and is probably due to the build up of contaminants on the surface. (△) 10-carbon chain alkylsiloxane. (▽) 12-carbon chain alkylsiloxane. (□) 18-carbon chain alkylsiloxane. The inset shows a schematic diagram of the scattering vectors for the specular reflectivity condition, where  $2(\phi) = 2\theta$ .

# Refraction including absorption



$$n = 1 - \delta + i\beta$$

wave propagating in a medium:

$$\exp(inkz) = \exp(i(1-\delta)kz) \exp(-\beta kz)$$

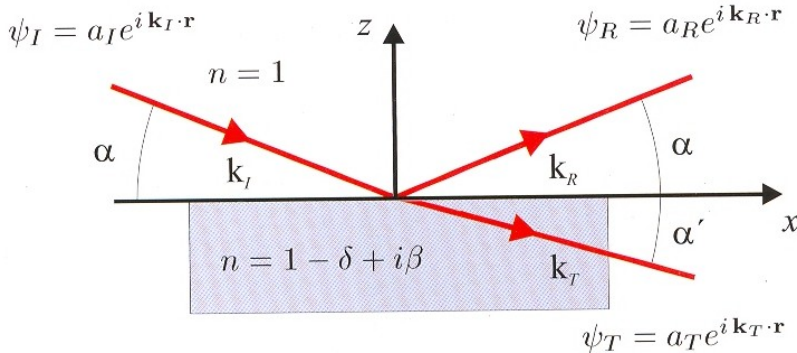
attenuation of amplitude:  $\exp(-\mu z/2)$   
 (when intensity drops according to  $\exp(-\mu z)$ )

$$\beta = \mu/2k$$

# Snell's law and the Fresnel equations

# Snell's law and the Fresnel equations

$$k = |\mathbf{k}_I| = |\mathbf{k}_R|$$



$$|\mathbf{k}_T| = nk$$

$$\parallel: a_I k \cos \alpha + a_R k \cos \alpha = a_T (nk) \cos \alpha' \quad (B')$$

$$\perp: -(a_I - a_R) k \sin \alpha = -a_T (nk) \sin \alpha' \quad (B'')$$

$$\boxed{\cos \alpha = n \cos \alpha'} \quad (B' + A)$$

$\alpha, \alpha'$  small: ( $\cos z = 1 - z^2/2$ )

$$\begin{aligned} \alpha^2 &= \alpha'^2 + 2\delta - 2i\beta \\ &= \alpha'^2 + \alpha_c^2 - 2i\beta \end{aligned} \quad (C)$$

$$a_I - a_R / a_I + a_R = n(\sin \alpha' / \sin \alpha) \approx \alpha' / \alpha \quad (B'' + A)$$

Require that the wave and its derivative is continuous at the interface:

$$a_I + a_R = a_T \quad (A)$$

$$a_I \mathbf{k}_I + a_R \mathbf{k}_R = a_T \mathbf{k}_T \quad (B)$$

Fresnel equations:

$$r = a_R / a_I = (\alpha - \alpha') / (\alpha + \alpha')$$

$$t = a_T / a_I = 2\alpha / (\alpha + \alpha')$$

r: reflectivity t: transmittivity

# Snell's law and the Fresnel equations (2)

Note:  $\alpha'$  is a complex number

$$\alpha' = \text{Re}(\alpha') + i \text{Im}(\alpha')$$

Consider z-component of transmitted wave:

$$= a_T \exp(iks \sin \alpha' z) \approx a_T \exp(ik \alpha' z)$$

$$= a_T \exp(ik \text{Re}(\alpha') z) \cdot \exp(-k \text{Im}(\alpha') z)$$



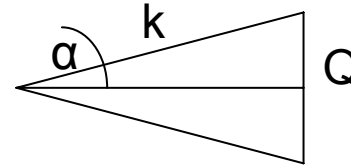
exponential damping

intensity fall-off:  $\exp(-2k \text{Im}(\alpha') z)$

1/e penetration depth  $\Lambda$ :  $z = 2k \text{Im}(\alpha') = 1$  ( $z = \Lambda$ )

$$\Lambda = 1 / 2k \text{Im}(\alpha')$$

use wavevector notation:



$$\sin \alpha = (Q/2)/k$$

$$Q \equiv 2k \sin \alpha \approx 2k \alpha$$

$$Q_c \equiv 2k \sin \alpha_c \approx 2k \alpha_c$$

use dimensionless units:

$$q \equiv Q/Q_c \approx (2k/Q_c) \alpha$$

$$q' \equiv Q'/Q_c \approx (2k/Q_c) \alpha'$$

$$q^2 = q'^2 + 1 - 2i b_u \quad (D)$$

$$b_u = (2k/Q_c) \beta = (4k^2/Q_c^2) \mu / 2k = 2k \mu / Q_c^2$$

$$Q_c = 2k \alpha_c = 2k \sqrt{2\delta}$$

# Snell's law and the Fresnel equations (3)

use table to extract  $\mu$ ,  $\rho$ ,  $f'$  yielding  $Q_c$   
and calculate  $b_u$  ( $b_u \ll 1$ ):

$$b_u = 2k\mu/Q_c^2$$

use (D):  $q^2 = q'^2 + 1 - 2ib_u$

	Z	Molar density (g/mole)	Mass density (g/cm <sup>3</sup> )	$\rho$ (e/Å <sup>3</sup> )	$Q_c$ (1/Å)	$\mu \times 10^6$ (1/Å)	$b_\mu$
C	6	12.01	2.26	0.680	0.031	0.104	0.0009
Si	14	28.09	2.33	0.699	0.032	1.399	0.0115
Ge	32	72.59	5.32	1.412	0.045	3.752	0.0153
Ag	47	107.87	10.50	2.755	0.063	22.128	0.0462
W	74	183.85	19.30	4.678	0.081	33.235	0.0409
Au	79	196.97	19.32	4.666	0.081	40.108	0.0495

get:

$$r(q) = (q - q') / (q + q')$$

$$t(q) = 2q / (q + q')$$

$$\Lambda(q) = 1 / Q_c \operatorname{Im}(q')$$

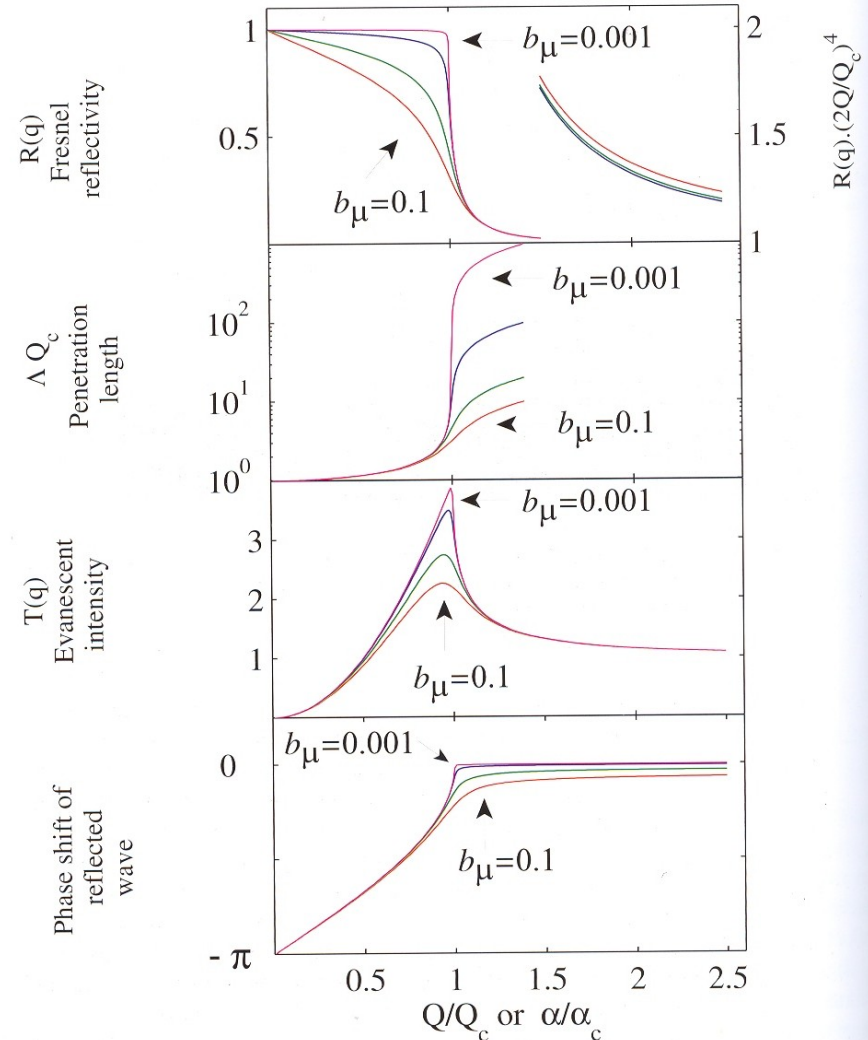
# Snell's law and the Fresnel equations (4)

## Fresnel equations:

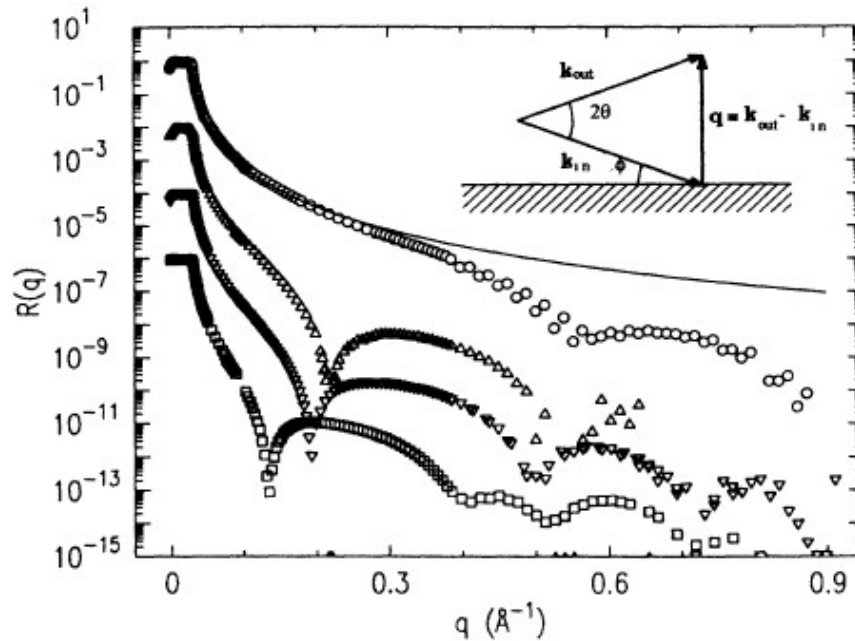
$q \gg 1$ :  $R(Q) \sim 1/q^4$ ,  
 $\Lambda \approx \mu^{-1}$ ,  
 $T \approx 1$ ,  
 no phase shift

$q \ll 1$ :  $R \approx 1$ ,  
 $\Lambda \approx 1/q_c$  small,  
 $T$  very small,  
 $-\pi$  phase shift

$q = 1$ :  $T(q=1) \approx 4 a_1$



# Examples



PHYSICAL REVIEW B

VOLUME 41, NUMBER 2

15 JANUARY 1990-I

## X-ray specular reflection studies of silicon coated by organic monolayers (alkylsiloxanes)

I. M. Tidswell, B. M. Ocko,\* and P. S. Pershan

*Division of Applied Sciences and Department of Physics, Harvard University, Cambridge, Massachusetts 02138*

S. R. Wasserman and G. M. Whitesides

*Department of Chemistry, Harvard University, Cambridge, Massachusetts 02138*

J. D. Axe

*Department of Physics, Brookhaven National Laboratory, Upton, New York 11973*

(Received 3 October 1988; revised manuscript received 7 August 1989)

FIG. 1. Normalized reflectivity data from several samples. Successive data sets are displaced by 100 times and error bars omitted for clarity. (—) Theoretical reflectivity from an ideal step interface with bulk silicon density. (○) Uncoated silicon sample in helium; the “pairing” of points occurs for two scans taken 60 min apart and is probably due to the build up of contaminants on the surface. (△) 10-carbon chain alkylsiloxane. (▽) 12-carbon chain alkylsiloxane. (□) 18-carbon chain alkylsiloxane. The inset shows a schematic diagram of the scattering vectors for the specular reflectivity condition, where  $2(\phi) = 2\theta$ .



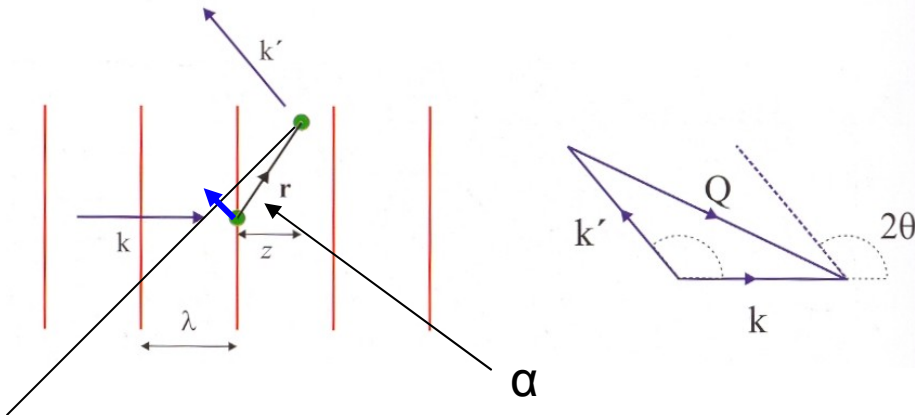
# Kinematical Diffraction

# Kinematical Diffraction

One of the main applications of X-rays is the determination of structure(s) using diffraction.

Assume the scattering to be weak; multiple scattering effects are to be neglected: weak scattering limit  $\equiv$  kinemtical approximation.

Consider a 2 electron system:



$$z = r \cos \alpha; \quad k z = k r \cos \alpha = \mathbf{k} \cdot \mathbf{r}$$

$$y = r \cos \beta; \quad k' y = k' r \cos \beta = \mathbf{k}' \cdot \mathbf{r}$$

path- or phase difference:

$$\Delta \Phi = z - y = \mathbf{k} \cdot \mathbf{r} - \mathbf{k}' \cdot \mathbf{r} = \mathbf{Q} \cdot \mathbf{r}$$

with

$$Q = (4\pi/\lambda) \sin \theta$$

scattering amplitude for 2 electrons:

$$A(\mathbf{Q}) = -r_0 [1 + \exp(i\mathbf{Q}\mathbf{r})]$$

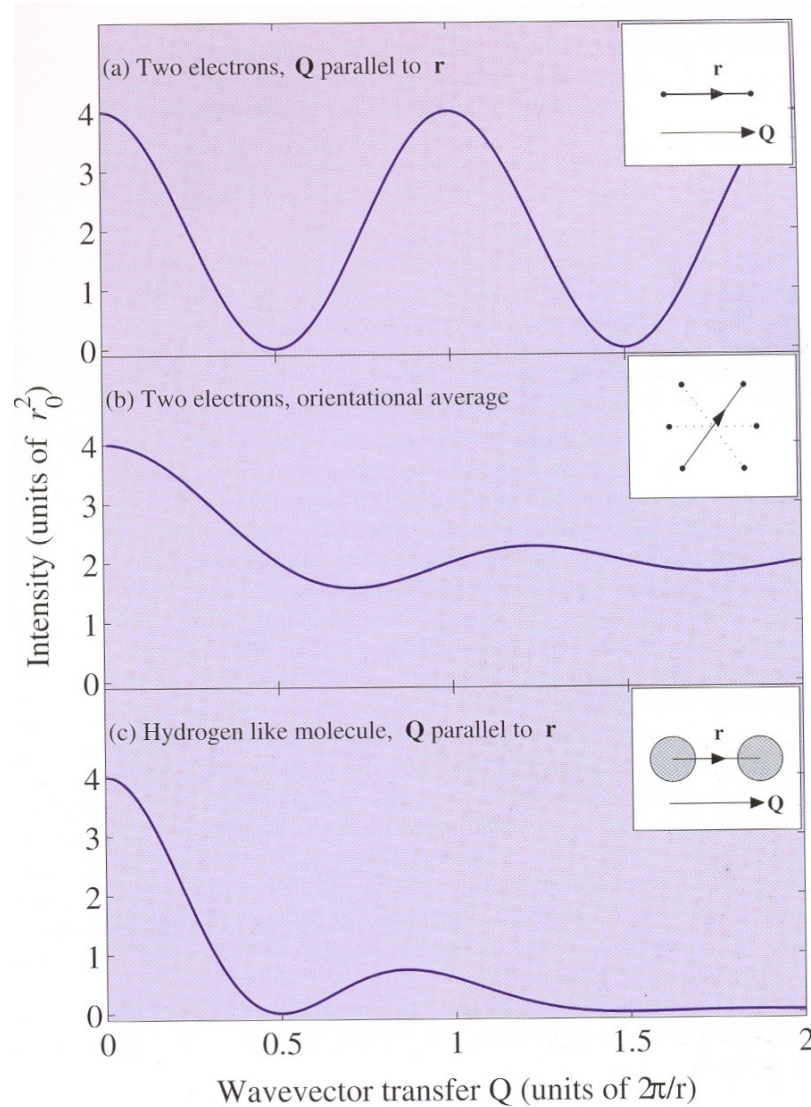
$$\begin{aligned} I(\mathbf{Q}) &= A(\mathbf{Q}) A(\mathbf{Q})^* \\ &= 2r_0^2 [1 + \cos(Qr)] \end{aligned}$$

see Fig. 4.2

for many electrons:

$$A(\mathbf{Q}) = -r_0 \sum_j \exp(i\mathbf{Q}\mathbf{r}_j)$$

# Kinematical Diffraction

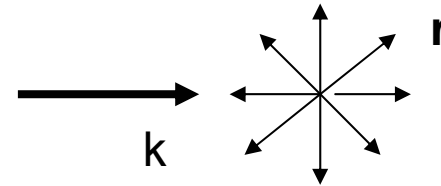


Two electron system:

$$I(Q) = 2r_0^2 [1 + \cos(Qr)]$$

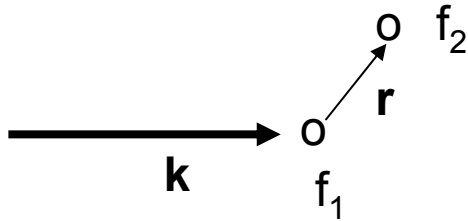
$$Q \parallel r$$

orientational average



“smeared”, no more “point-like” particles

for many systems, e.g. molecules the orientation of  $\mathbf{r}$  will be random wrt  $\mathbf{k}$



Orientational averaging: assume one electron at  $r=0$ , a second at  $r$

$$A(Q) = f_1 + f_2 \exp(i\mathbf{Q}\mathbf{r})$$

$$I(Q) = f_1^2 + f_2^2 + f_1 f_2 \exp(i\mathbf{Q}\mathbf{r}) + f_1 f_2 \exp(-i\mathbf{Q}\mathbf{r})$$

orientational averaging:  $\langle \exp(i\mathbf{Q}\mathbf{r}) \rangle = \langle \exp(-i\mathbf{Q}\mathbf{r}) \rangle$

$$\langle I(Q) \rangle = f_1^2 + f_2^2 + 2f_1 f_2 \langle \exp(i\mathbf{Q}\mathbf{r}) \rangle$$

$$\langle \exp(i\mathbf{Q}\mathbf{r}) \rangle = \frac{\int \exp(iQr \cos\theta) \sin\theta \, d\theta d\Phi}{\int \sin\theta \, d\theta d\Phi} \leftarrow 4\pi$$

$$\int \exp(iQr \cos\theta) \sin\theta \, d\theta d\Phi$$

$$= 2\pi \int \exp(iQr \cos\theta) \sin\theta \, d\theta$$

$$= 2\pi (-1/iQr) \int_{iQr}^{-iQr} \exp(x) \, dx$$

$$= 4\pi \sin(Qr)/Qr$$

$$\langle I(Q) \rangle = f_1^2 + f_2^2 + 4\pi f_1 f_2 \sin(Qr)/Qr$$

see figure 4.2 b

if the position of the electrons distributed or smeared: see Figure 4.2c

# Scattering from an atom:

scattering amplitude of an atom  $\equiv$  atomic form factor  $f_0(Q)$  [in units of  $r_0$ ]

$\rho(r)$ : electronic number density  $\equiv$  charge density

$$f_0(Q) = \int \rho(r) \exp(i\mathbf{Q}r) dr$$

$$= \begin{cases} Z & Q \rightarrow 0 \\ 0 & Q \rightarrow \infty \end{cases}$$

note: atomic form factor is FT of electronic charge distribution

$f_0(Q/4\pi)$  tabulated:

$$f_0(Q/4\pi) = \sum_{j=1}^4 a_j \exp -b_j(Q/4\pi)^2 + c$$

	$a_1$	$b_1$	$a_2$	$b_2$	$a_3$	$b_3$	$a_4$	$b_4$	$c$
C	2.3100	20.8439	1.0200	10.2075	1.5886	0.5687	0.8650	51.6512	0.2156
O	3.0485	13.2771	2.2868	5.7011	1.5463	0.3239	0.8670	32.9089	0.2508
F	3.5392	10.2825	2.6412	4.2944	1.5170	0.2615	1.0243	26.1476	0.2776
Si	6.2915	2.4386	3.0353	32.333	1.9891	0.6785	1.5410	81.6937	1.1407
Cu	13.338	3.5828	7.1676	0.2470	5.6158	11.3966	1.6735	64.820	1.5910
Ge	16.0816	2.8509	6.3747	0.2516	3.7068	11.4468	3.683	54.7625	2.1313
Mo	3.7025	0.2772	17.236	1.0958	12.8876	11.004	3.7429	61.6584	4.3875

table 4.1: J. Als-Nielsen & D. McMorrow

note:

$$f = f_0(Q) + f' + f''$$

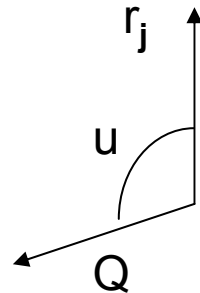
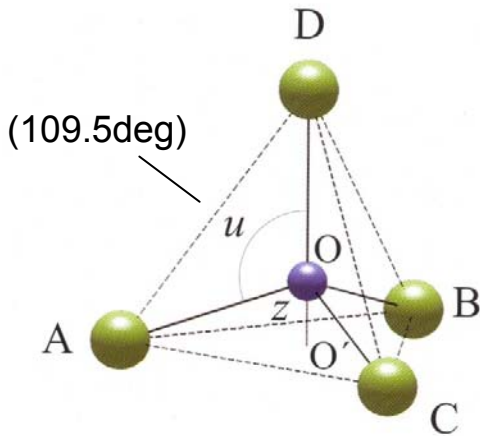
corrections  $f'$  and  $f''$  arise from the fact that the electrons are bound in the atom

# Scattering from a molecule:

$$F^{\text{mol}}(\mathbf{Q}) = \sum_{r_j} f_j(\mathbf{Q}) \exp(i\mathbf{Q}r_j)$$

example: CF<sub>4</sub>:

assume OA=OB=OC=OD=1; z=OO'=cos(u)=1/3

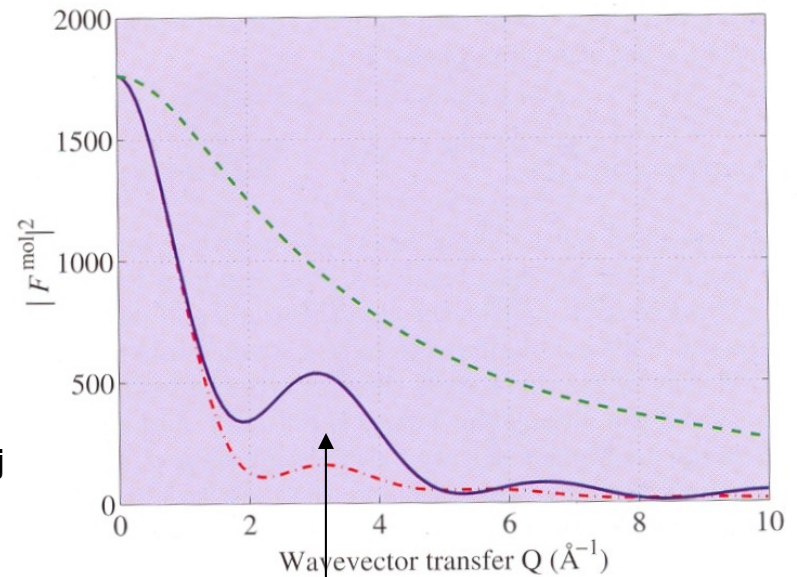


$$\mathbf{Q}r_j = Qr_j \cos(u) = (1/3)Qr_j$$

Assume: Q || C-F bond

$$\begin{aligned} F^{\text{mol}} &= f^{\text{C}}(\mathbf{Q}) + f^{\text{F}}(\mathbf{Q}) [\exp(i\mathbf{Q}R) + 3\exp(i\mathbf{Q}r_j)] \\ &= f^{\text{C}}(\mathbf{Q}) + f^{\text{F}}(\mathbf{Q}) [3\exp(-/+i\mathbf{Q}R/3) + \exp(+/-i\mathbf{Q}R)] \end{aligned}$$

- CF<sub>4</sub>
- . - . - CF<sub>4</sub> Q not || C-F
- - - - molybdenum (also 42 electrons)



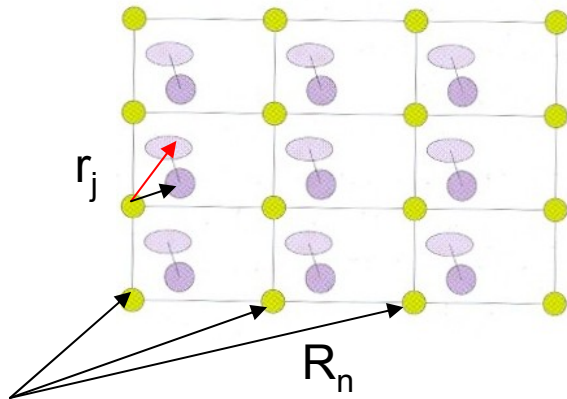
(F-F bond)

# Scattering from a crystal

$$A(\mathbf{Q}) = -r_0 \sum_{\mathbf{r}_j} \exp(i \mathbf{Q} \mathbf{r}_j')$$

an extension to crystalline matter is simplified since there is translational symmetry.

$$\text{crystalline matter: } \mathbf{r}_j' = \mathbf{R}_n + \mathbf{r}_j$$



$$A(\mathbf{Q}) = -r_0 \underbrace{\sum_{\mathbf{R}_n} \exp(i \mathbf{Q} \mathbf{R}_n)}_{\text{lattice sum}} \underbrace{\sum_{\mathbf{r}_j} \exp(i \mathbf{Q} \mathbf{r}_j)}_{\text{unit cell structure factor}}$$

lattice sum

unit cell structure factor

Crystallography:

determine electron density within unit cell

Note: one does measure  $I(\mathbf{Q}) = A(\mathbf{Q}) A^*(\mathbf{Q})$  and is thus not sensitive to phase shifts



# Scattering from a crystal

Scattering from atoms on a crystal lattice

Lattice planes and Miller indices

Laue conditions and reciprocal space

Reciprocal Lattice

The Ewald sphere

The unit cell structure factor

The unit cell structure factor for a fcc lattice

Lattice sums